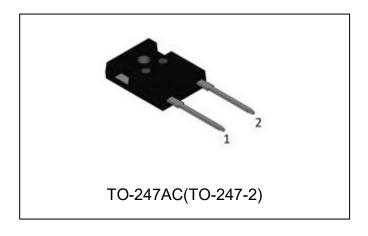






## S3D60065H2 650V SIC POWER SCHOTTKY RECTIFIER



#### **Description**

This 650V 60A diode is high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D60065H2 is ideal for energy sensitive, high frequency applications in challenging environments.

#### **Circuit Diagram**



#### **Features**

- 175°C T<sub>J</sub> operation
- Ultra-low switching loss
- · Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- "-A" is an AEC-Q101 qualified device
- Terminals finish: 100% Pure Tin
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

#### **Applications**

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- · Switching supply output rectification
- Reverse polarity protection







## **Maximum Ratings:**

Characteristics	Symbol Condition		Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>DC</sub>	-	650	V
	I <sub>F (AV)1</sub>	Tc=25°C	128	Α
Average Rectified Forward Current	I <sub>F (AV)2</sub>	Tc=125°C	70	Α
	I <sub>F (AV)3</sub>	Tc=138°C	60	Α
Repetitive Peak Forward Surge Current	I <sub>FRM1</sub>	10ms, Half Sine pulse, T <sub>C</sub> =25°C	240	Α
Trepentive Fear Forward Surge Surfern	I <sub>FRM2</sub>	10ms, Half Sine pulse, T <sub>C</sub> =110°C	160	Α
Deals One Civile New Benefitive Come Comment	I <sub>FSM1</sub>	10ms, Half Sine pulse, T <sub>C</sub> =25°C	500	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM2</sub>	10ms, Half Sine pulse, T <sub>C</sub> =110°C	340	А
Dower Dissination	P <sub>tot1</sub>	T <sub>C</sub> =25°C	484	W
Power Dissipation	P <sub>tot2</sub>	T <sub>C</sub> =110°C	209	W

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 60A, Pulse, T <sub>J</sub> = 25 °C	1.4	1.7	V
The state of the s	$V_{F2}$	@ 60A, Pulse, T <sub>J</sub> = 175 °C	1.6	2.0	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_J = 25 ^{\circ}\text{C}$	8	50	uA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R,} T_J = 175 ^{\circ}\text{C}$	80	200	uA
Junction Capacitance	Ст	V <sub>R</sub> =0V, T <sub>J</sub> =25℃, f=1MHz	4600	-	pF
Reverse Recovery Charge	Qc	$I_F$ = 60A, di/dt=200A/ $\mu$ s VR = 400 V, T <sub>J</sub> =25°C	286.9	-	nC
Capacitance Stored Energy		V <sub>R</sub> = 400 V, T <sub>J</sub> =25°C	70.3	-	μJ

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	S3D60065H2	Units
Junction Temperature	TJ	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	0.31	°C/W

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



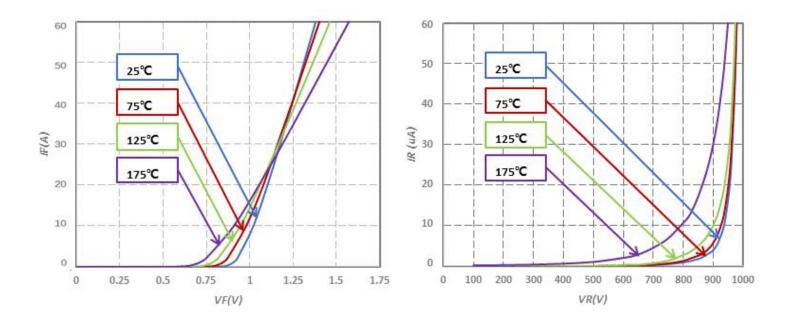




## **Ordering Information**

Device	Package	Plating	Shipping
S3D60065H2	TO-247AC(TO-247-2)	Pure Sn	25pcs / tube

#### **Ratings and Characteristics Curves**



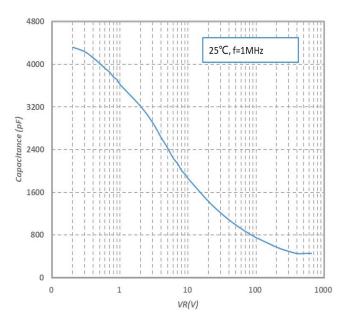
**Fig.1-Typical Forward Voltage Characteristics** 

Fig.2-Typical Reverse Characteristics









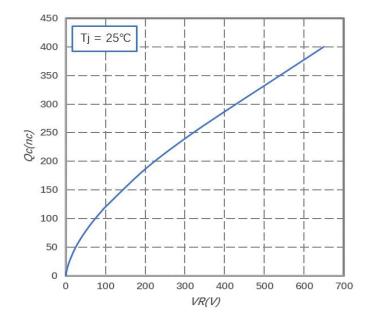
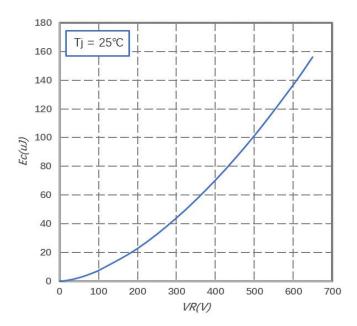


Fig.3-Capacitance vs. Reverse Voltage

Fig.4-Total Capacitance Charge vs. Reverse Voltage



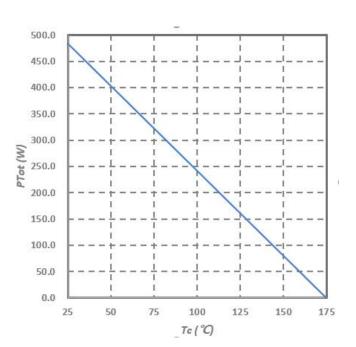


Fig.5-Capacitance Stored Energy

Fig.6-Power Derating

<sup>•</sup> China - Germany - Korea - Singapore - United States •

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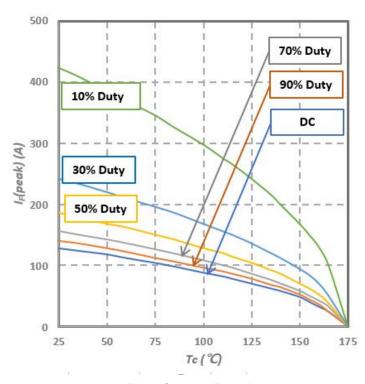


Fig.7-Current Derating

## **Marking Diagram**



Where XXXXX is YYWWL

 S3D
 = Device Type

 H
 = Package type

 60
 = Forward Current (60A)

 065
 = Reverse Voltage (650V)

 SSG
 = SSG

 YY
 = Year

WW = Week
L = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

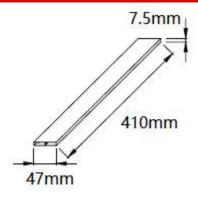
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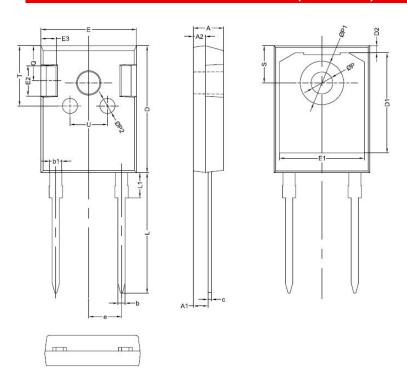


## **Tube Specification**



TO-247AC(TO-247-2)

#### **Mechanical Dimensions TO-247AC(TO-247-2)**



OVMDOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.10	1.20	1.35	
b1	1.80	2.00	2.20	
С	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.58		
D2 E		1.17		
Е	15.60	15.80	16.00	
E1		14.02		
E2		5.00		
E3		2.50		
е		5.44		
L	19.42	19.92	20.42	
L1		4.13		
Р	3.50	3.60	3.70	
P1	7.1	7.19	7.40	
P2		2.50		
Q		5.80		
Q S	6.05	6.15	6.25	
T		10.00		
U		6.20		







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